



DDTB (LO-R1) U

PNP PRE-BIASED 500 mA SURFACE MOUNT TRANSISTOR

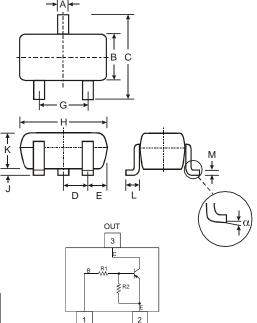
Features

- Epitaxial Planar Die Construction
- Complementary NPN Types Available (DDTD)
- Built-In Biasing Resistors
- Lead Free/RoHS Compliant (Note 2)
- "Green" Device (Note 3 & 4)

Mechanical Data

- Case: SOT-323
- Case Material: Molded Plastic, "Green" Molding Compound, Note 4. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminals: Solderable per MIL-STD-202, Method 208
- Terminal Connections: See Diagram
- Lead Free Plating (Matte Tin Finish annealed over Alloy 42 leadframe)
- Marking Information: See Table Below & Page 3
- Ordering Information: See Page 3
- Weight: 0.006 grams (approximate)

P/N	R1 (NOM)	R2 (NOM)	Type Code
DDTB122LU	0.22KΩ	10ΚΩ	P75
DDTB142JU	0.47ΚΩ	10ΚΩ	P76
DDTB122TU	0.22KΩ	OPEN	P77
DDTB142TU	0.47ΚΩ	OPEN	P78



GND(+)

Schematic and Pin Configuration

IN

SOT-323								
Dim	Min	Max						
Α	0.25 0.40							
В	1.15	1.35						
С	2.00	2.20						
D	0.65 N	lominal						
E	0.30 0.40							
G	1.20 1.40							
Н	1.80 2.20							
J	0.0 0.10							
K	0.90 1.00							
L	0.25 0.40							
М	0.10 0.18							
α	0° 8°							
All Dimensions in mm								

Maximum Ratings @T_A = 25°C unless otherwise specified

Characteristic		Symbol	Value	Unit	
Supply Voltage, (3) to (2)		V _{CC}	-50	V	
Input Voltage, (1) to (2)	DDTB122LU DDTB142JU	V _{IN}	+5 to -6 +5 to -6	V	
Input Voltage, (2) to (1)	DDTB122TU DDTB142TU	V _{EBO} (MAX)	-5	V	
Output Current	All	I _C	-500	mA	
Power Dissipation	(Note 1)	P_d	200	mW	
Thermal Resistance, Junction to Ambient Air	(Note 1)	$R_{ hetaJA}$	625	°C/W	
Operating and Storage Temperature Range		T_j , T_{STG}	-55 to +150	°C	

Notes:

- 1. Mounted on FR4 PC Board with recommended pad layout at http://www.diodes.com/datasheets/ap02001.pdf.
- No purposefully added lead.
- 3. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.
- Product manufactured with Date Code 0627 (week 27, 2006) and newer are built with Green Molding Compound. Product manufactured prior to Date Code 0627 are built with Non-Green Molding Compound and may contain Halogens or Sb2O3 Fire Retardants.



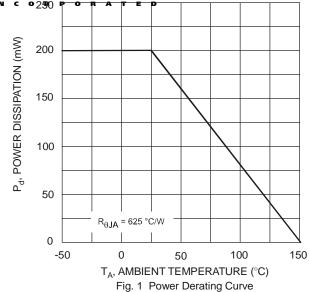
R1, R2 Types **Electrical Characteristics** @T_A = 25°C unless otherwise specified Characteristic **Symbol** Min Тур Max Unit **Test Condition** DDTB122LU -0.3 ٧ $V_{I(off)}$ V_{CC} = -5V, I_{O} = -100 μA DDTB142JU -0.3 Input Voltage DDTB122LU -2.0 $V_O = -0.3V$, $I_O = -20mA$ ٧ $V_{l(on)}$ DDTB142JU -2.0 $V_0 = -0.3V$, $I_0 = -20mA$ $V_{O(on)} \\$ Output Voltage -0.3V $I_0/I_1 = -50 \text{mA}/-2.5 \text{mA}$ DDTB122LU Input Current $V_1 = -5V$ I_{\parallel} mΑ DDTB142JU -13 Output Current -0.5 $V_{CC} = -50V, V_{I} = 0V$ $I_{O(off)}$ μΑ DDTB122LU 56 DC Current Gain G_I $V_O = -5V$, $I_O = -50mA$ DDTB142JU 56 Gain-Bandwidth Product* f_T 200 MHz $V_{CE} = -10V$, $I_E = -5mA$, f = 100MHz

^{*} Transistor - For Reference Only

Electrical Characteristic	@T _A = 25°C unless otherwise specified					R1 – Only Types		
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition		
Collector-Base Breakdown Voltage		BV _{CBO}	-50	_	_	V	I _C = -50μA	
Collector-Emitter Breakdown Voltage		BV _{CEO}	-40	_	_	V	I _C = -1mA	
Emitter-Base Breakdown Voltage	BV _{EBO}	-5	_	_	V	I _E = -50μA I _E = -50μA		
Collector Cutoff Current		I _{CBO}	_	_	-0.5	μА	V _{CB} = -50V	
Emitter Cutoff Current DDTB122TU DDTB142TU		I _{EBO}	_	_	-0.5 -0.5	μА	V _{EB} = -4V	
Collector-Emitter Saturation Voltage		V _{CE(sat)}	_	_	-0.3	V	I _C = -50mA, I _B = -2.5mA	
DC Current Transfer Ratio	DDTB122TU DDTB142TU	h _{FE}	100 100	250 250	600 600	_	$I_{C} = -5mA, V_{CE} = -5V$	
Gain-Bandwidth Product*	•	f _T	_	200		MHz	V _{CE} = -10V, I _E = 5mA, f = 100MHz	

^{*} Transistor - For Reference Only



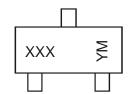


Ordering Information (Note 4 & 5)

Device	Packaging	Shipping		
DDTB122LU-7-F	SOT-323	3000/Tape & Reel		
DDTB142JU-7-F	SOT-323	3000/Tape & Reel		
DDTB122TU-7-F	SOT-323	3000/Tape & Reel		
DDTB142TU-7-F	SOT-323	3000/Tape & Reel		

Notes: 5. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information



XXX = Product Type Marking Code (See Page 1)

YM = Date Code Marking

Y = Year ex: T = 2006

M = Month ex: 9 = September

Date Code Key

Year	2006	2007	2008	2009	2010	2011	2012
Code	Т	U	V	W	X	Υ	Z

Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D

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